



300V NPN SMALL-SIGNAL TRANSISTOR IN SOT323

Description

This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirements of automotive applications.

Features

- BVcEo > 300V
- Ic = 200mA High Collector Current
- Complementary PNP Type Available: MMSTA92Q
- Ideal for Low Power Amplification and Switching
- Totally Lead-Free & Fully RoHS Compliant (Note 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The MMSTA42Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

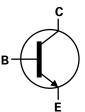
Mechanical Data

- Package: SOT323
- Package Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (23)
- Weight 0.006 grams (Approximate)

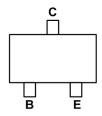
SOT323



Top View



Device Symbol



Top View Pinout

Ordering Information (Note 4)

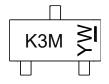
Orderable Bort Number	Dookowa	Mouking	Reel Size	Reel Size Tape Width		king
Orderable Part Number	Package	Marking	(inches)	(mm)	Qty.	Carrier
MMSTA42Q-7	SOT323	K3M	7	8	3.000	Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

SOT323



K3M = Product Type Marking Code Y<u>W</u> = Date Code Marking Y = Year (ex: M = 2025) <u>W</u> = Week 0 to 53

Date Code Key - Year

Year	2025	2026	2027	2028	2029	2030	2031	2032	2033	2034	2035	2036
Code	М	N	Р	R	S	Т	U	V	W	X	Υ	Z



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	Vcво	300	V
Collector-Emitter Voltage	V _{CEO}	300	V
Emitter-Base Voltage	VEBO	6	V
Continuous Collector Current	lc	200	mA

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	PD	200	mW
Thermal Resistance, Junction to Ambient	(Note 5)	Reja	625	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge – Charged Device Model	ESD CDM	1000	V	C3

Notes:

^{5.} For a device mounted on the minimum recommended pad layout on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady state.

6. Refer to JEDEC specifications JESD22-A114 and JESD22-C101.



Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

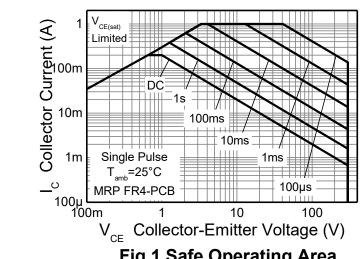


Fig.1 Safe Operating Area

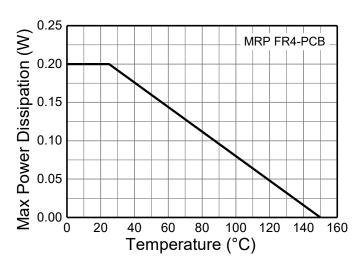


Fig.2 Derating Curve

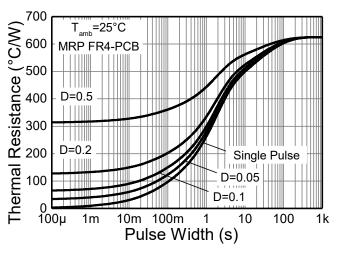


Fig.3 Transient Thermal Impedance

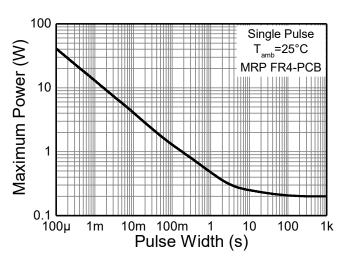


Fig.4 Pulse Power Dissipation

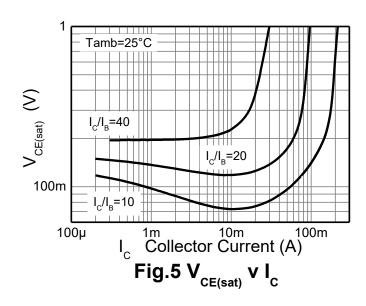


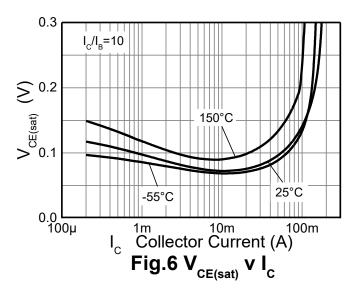
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Emitter Breakdown Voltage (Note 7)	BVCEO	300		_	V	Ic = 1mA
Collector-Base Breakdown Voltage	ВУсво	300	_	_	V	I _C = 100μA
Emitter-Base Breakdown Voltage	BV _{EBO}	6	_	_	V	I _E = 100μA
Collector-Base Cutoff Current	Ісво	_	_	100	nA	V _{CB} = 200V
Emitter-Base Cutoff Current	IEBO	_	_	100	nA	V _{CE} = 5V
ON CHARACTERISTICS						
		25				$I_C = 1mA, V_{CE} = 10V$
DC Current Gain (Note 7)	hfE	40	_	_	_	Ic = 10mA, VcE = 10V
		40				Ic = 30mA, VcE = 10V
Collector-Emitter Saturation Voltage (Note 7)	V _{CE(sat)}	_	_	500	mV	I _C = 20mA, I _B = 2mA
Base-Emitter Voltage (Note 7)	V _{BE(sat)}	_	_	900	mV	Ic = 20mA, I _B = 2mA
SMALL-SIGNAL CHARACTERISTICS						
Input Capacitance	Cibo	_	80	_	pF	V _{EB} = 0.5V, f = 1MHz
Output Capacitance	C _{obo}	_	3	6	pF	V _{CB} = 20V, f = 1MHz
Current Gain Bandwidth Product	f⊤	50	83	_	MHz	V _{CE} = 20V, I _C = 10mA, f = 100MHz
Turn-On Time	td	_	124	_	ns	
	tr		88		ns	V _{CC} = 20V, I _C = 10mA,
Turn-Off Time	ts		3168		ns	$I_{B1} = -I_{B2} = 1mA$
	t _r	_	223	_	ns	

Note:

7. Measured under pulsed conditions. Pulse width $\leq 300 \mu s.$ Duty cycle $\leq\!\!2\%.$

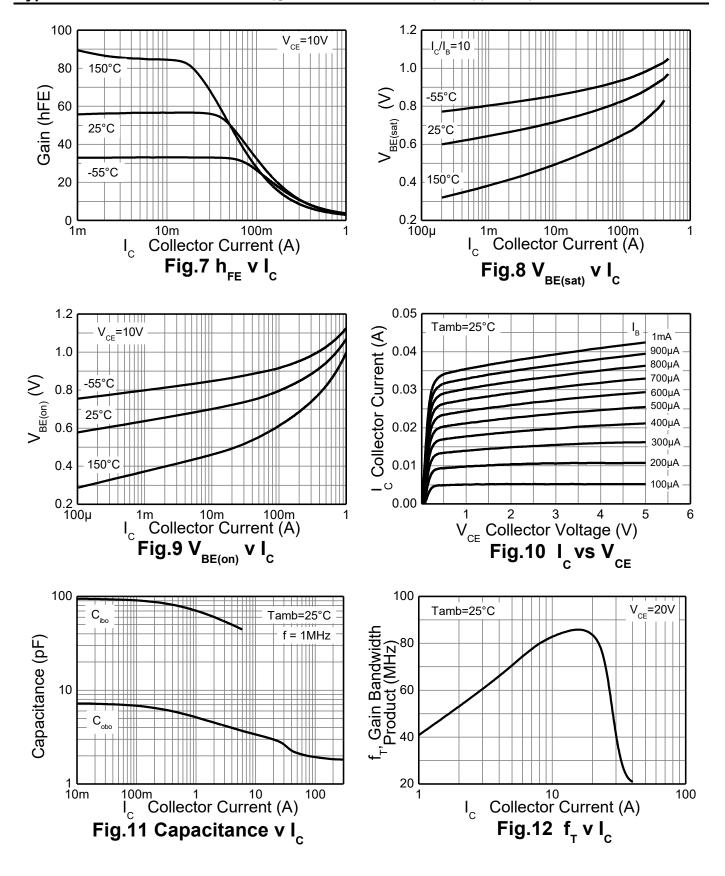
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)







Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.) (continued)

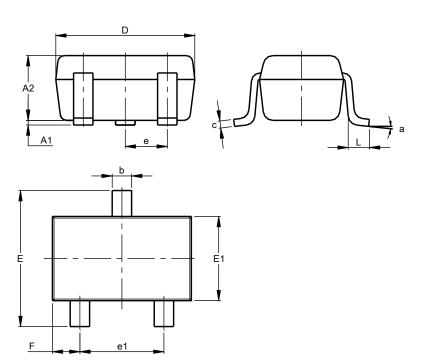




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT323

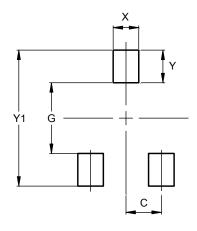


SOT323						
Dim	Min	Max	Тур			
A1	0.00	0.10	0.05			
A2	0.90	1.00	0.95			
b	0.25	0.40	0.30			
С	0.10	0.18	0.11			
D	1.80	2.20	2.15			
Е	2.00	2.20	2.10			
E1	1.15	1.35	1.30			
е	C).650 B	SC			
e1	1.20	1.40	1.30			
F	0.375	0.475	0.425			
L	0.25	0.40	0.30			
а	0°	8°				
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT323



Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.470
Υ	0.600
V1	2 500



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